## NSN 5961-00-154-6966

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View Online at https://aerobasegroup.com/nsn/5961-00-154-6966 **Inclosure Material:** Metal **Overall Length:** 0.420 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.625 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 off-state voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0